

# ND2406L/2410L, BSS129

## N-Channel Depletion-Mode MOSFET Transistors

### Product Summary

| Part Number | $V_{(BR)DSV}$ Min (V) | $r_{DS(on)}$ Max ( $\Omega$ ) | $V_{GS(off)}$ (V) | $I_D$ (A) |
|-------------|-----------------------|-------------------------------|-------------------|-----------|
| ND2406L     | 240                   | 6                             | -1.5 to -4.5      | 0.23      |
| ND2410L     |                       | 10                            | -0.5 to -2.5      | 0.18      |
| BSS129      | 230                   | 20                            | -0.7 (min)        | 0.15      |

### Features

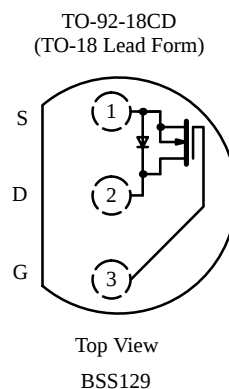
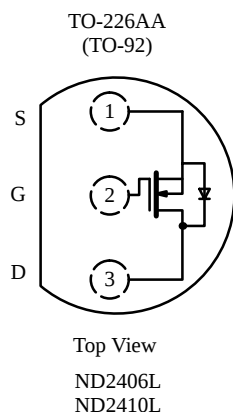
- High Breakdown Voltage: 260 V
- Normally "On" Low  $r_{DS}$  Switch: 3.5  $\Omega$
- Low Input and Output Leakage
- Low-Power Drive Requirement
- Low Input Capacitance

### Benefits

- Full-Voltage Operation
- Low Offset Voltage
- Low Error Voltage
- Easily Driven Without Buffer
- High-Speed Switching

### Applications

- Normally "On" Switching Circuits
- Current Sources/Limiters
- Power Supply, Converter Circuits
- Solid-State Relays
- Telecom Switches



### Absolute Maximum Ratings ( $T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

| Parameter                                              | Symbol         | ND2406L    | ND2410L  | BSS129   | Unit               |
|--------------------------------------------------------|----------------|------------|----------|----------|--------------------|
| Drain-Source Voltage                                   | $V_{DS}$       | 240        | 240      | 230      | V                  |
| Gate-Source Voltage                                    | $V_{GS}$       | $\pm 30$   | $\pm 30$ | $\pm 20$ |                    |
| Continuous Drain Current ( $T_J = 150^\circ\text{C}$ ) | $I_D$          | 0.23       | 0.18     | 0.15     | A                  |
|                                                        |                | 0.14       | 0.12     |          |                    |
| Pulsed Drain Current <sup>a</sup>                      | $I_{DM}$       | 0.9        | 0.9      | 0.6      |                    |
| Power Dissipation                                      | $P_D$          | 0.8        | 0.8      | 1.0      | W                  |
|                                                        |                | 0.32       | 0.32     | 0.4      |                    |
| Maximum Junction-to-Ambient                            | $R_{thJA}$     | 156        | 156      | 125      | $^\circ\text{C/W}$ |
| Operating Junction and Storage Temperature Range       | $T_J, T_{stg}$ | -55 to 150 |          |          | $^\circ\text{C}$   |

#### Notes

a. Pulse width limited by maximum junction temperature.

Updates to this data sheet may be obtained via facsimile by calling Siliconix FaxBack, 1-408-970-5600. Please request FaxBack document #70198. Applications information may also be obtained via FaxBack, request document #70612.

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## Specifications<sup>a</sup>

| Parameter                                     | Symbol               | Test Conditions                                                                                                            | Typ <sup>b</sup> | Limits  |      |         |      |        |       | Unit |
|-----------------------------------------------|----------------------|----------------------------------------------------------------------------------------------------------------------------|------------------|---------|------|---------|------|--------|-------|------|
|                                               |                      |                                                                                                                            |                  | ND2406L |      | ND2410L |      | BSS129 |       |      |
|                                               |                      |                                                                                                                            |                  | Min     | Max  | Min     | Max  | Min    | Max   |      |
| Static                                        |                      |                                                                                                                            |                  |         |      |         |      |        |       |      |
| Drain-Source Breakdown Voltage                | V <sub>(BR)DSV</sub> | V <sub>GS</sub> = -9 V, I <sub>D</sub> = 10 μA                                                                             | 260              | 240     |      |         |      |        |       | V    |
|                                               |                      | V <sub>GS</sub> = -5 V, I <sub>D</sub> = 10 μA                                                                             | 260              |         |      | 240     |      |        |       |      |
|                                               |                      | V <sub>GS</sub> = -3 V, I <sub>D</sub> = 250 μA                                                                            | 260              |         |      |         |      | 230    |       |      |
| Gate-Source Cutoff Voltage                    | V <sub>GS(off)</sub> | V <sub>DS</sub> = 5 V, I <sub>D</sub> = 10 μA                                                                              |                  | -1.5    | -4.5 | -0.5    | -2.5 |        |       |      |
|                                               |                      | V <sub>DS</sub> = 3 V, I <sub>D</sub> = 1 mA                                                                               |                  |         |      |         |      | -0.7   |       |      |
| Gate-Body Leakage                             | I <sub>GSS</sub>     | V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ± 20 V                                                                            |                  |         | ± 10 |         | ± 10 |        | ± 100 | nA   |
|                                               |                      | T <sub>J</sub> = 125°C                                                                                                     |                  |         | ± 50 |         | ± 50 |        |       |      |
| Drain Cutoff Current                          | I <sub>D(off)</sub>  | V <sub>DS</sub> = 180 V, V <sub>GS</sub> = -9 V                                                                            |                  |         | 1    |         |      |        |       | μA   |
|                                               |                      | T <sub>J</sub> = 125°C                                                                                                     |                  |         | 200  |         |      |        |       |      |
|                                               |                      | V <sub>DS</sub> = 180 V, V <sub>GS</sub> = -5 V                                                                            |                  |         |      |         | 1    |        |       |      |
|                                               |                      | T <sub>J</sub> = 125°C                                                                                                     |                  |         |      |         | 200  |        |       |      |
|                                               |                      | V <sub>DS</sub> = 230 V, V <sub>GS</sub> = -3 V                                                                            |                  |         |      |         |      |        | 0.1   |      |
| T <sub>J</sub> = 125°C                        |                      |                                                                                                                            |                  |         |      |         |      | 200    |       |      |
| Drain-Saturation Current <sup>c</sup>         | I <sub>DSS</sub>     | V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V                                                                              | 350              | 40      |      | 40      |      |        |       | mA   |
| Drain-Source On-Resistance <sup>c</sup>       | r <sub>DS(on)</sub>  | V <sub>GS</sub> = 2 V, I <sub>D</sub> = 30 mA                                                                              | 3.3              |         |      |         |      |        |       | Ω    |
|                                               |                      | V <sub>GS</sub> = 0 V, I <sub>D</sub> = 30 mA                                                                              | 4.5              |         | 6    |         | 10   |        |       |      |
|                                               |                      | T <sub>J</sub> = 125°C                                                                                                     | 7.2              |         | 15   |         | 25   |        |       |      |
|                                               |                      | V <sub>GS</sub> = 0 V, I <sub>D</sub> = 14 mA                                                                              | 4                |         |      |         |      |        | 20    |      |
| Forward Transconductance <sup>c</sup>         | g <sub>fs</sub>      | V <sub>DS</sub> = 25 V, I <sub>D</sub> = 250 mA                                                                            | 375              |         |      |         |      | 140    |       | mS   |
|                                               |                      |                                                                                                                            | 110              |         |      |         |      |        |       |      |
| Common Source Output Conductance <sup>c</sup> | g <sub>os</sub>      | V <sub>DS</sub> = 10 V, I <sub>D</sub> = 30 A                                                                              | 70               |         |      |         |      |        |       | μS   |
| Dynamic                                       |                      |                                                                                                                            |                  |         |      |         |      |        |       |      |
| Input Capacitance                             | C <sub>iss</sub>     | V <sub>DS</sub> = 25 V, V <sub>GS</sub> = -5 V<br>f = 1 MHz                                                                | 70               |         | 120  |         | 120  |        |       | pF   |
| Output Capacitance                            | C <sub>oss</sub>     |                                                                                                                            | 20               |         | 30   |         | 30   |        |       |      |
| Reverse Transfer Capacitance                  | C <sub>rss</sub>     |                                                                                                                            | 10               |         | 15   |         | 15   |        |       |      |
| Switching <sup>d</sup>                        |                      |                                                                                                                            |                  |         |      |         |      |        |       |      |
| Turn-On Time                                  | t <sub>d(on)</sub>   | V <sub>DD</sub> = 25 V, R <sub>L</sub> = 830 Ω<br>I <sub>D</sub> ≅ 30 mA, V <sub>GEN</sub> = -5 V<br>R <sub>G</sub> = 25 Ω | 15               |         |      |         |      |        |       | ns   |
|                                               | t <sub>r</sub>       |                                                                                                                            | 75               |         |      |         |      |        |       |      |
| Turn-Off Time                                 | t <sub>d(off)</sub>  |                                                                                                                            | 40               |         |      |         |      |        |       |      |
|                                               | t <sub>f</sub>       |                                                                                                                            | 100              |         |      |         |      |        |       |      |

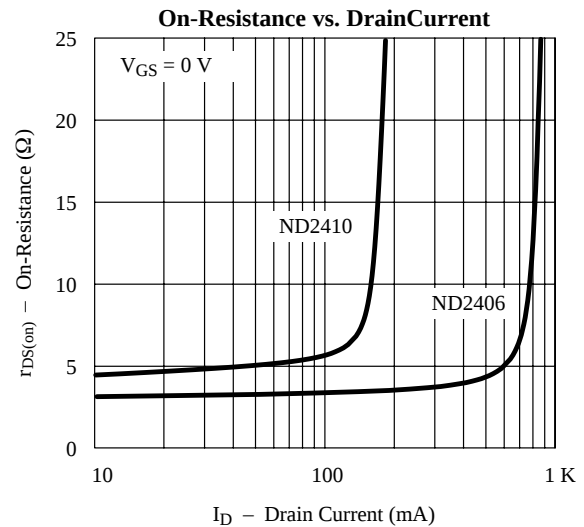
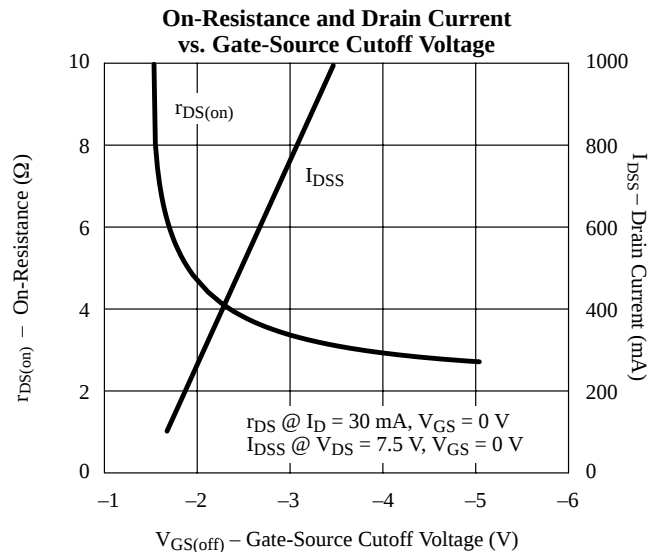
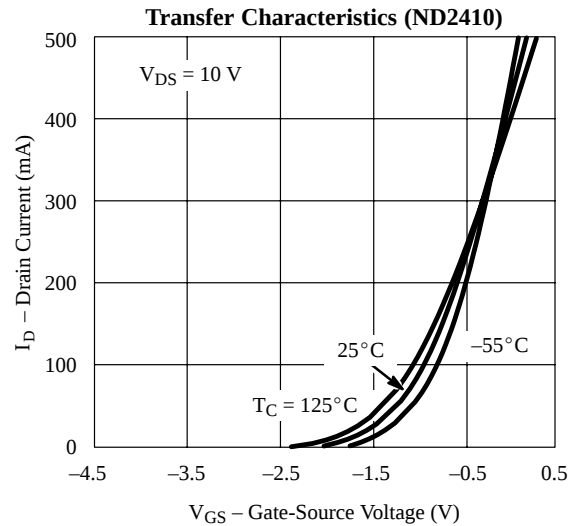
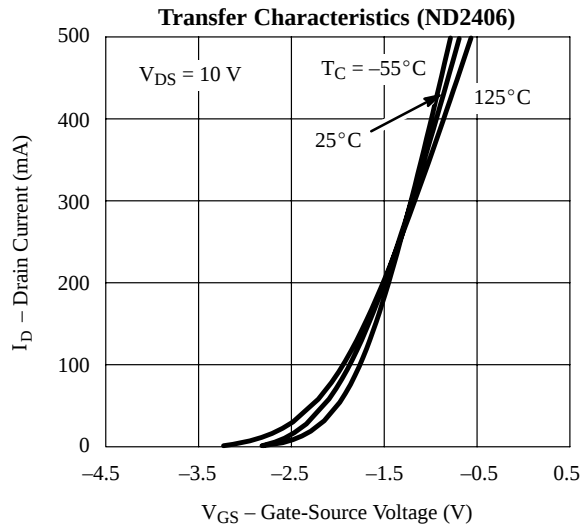
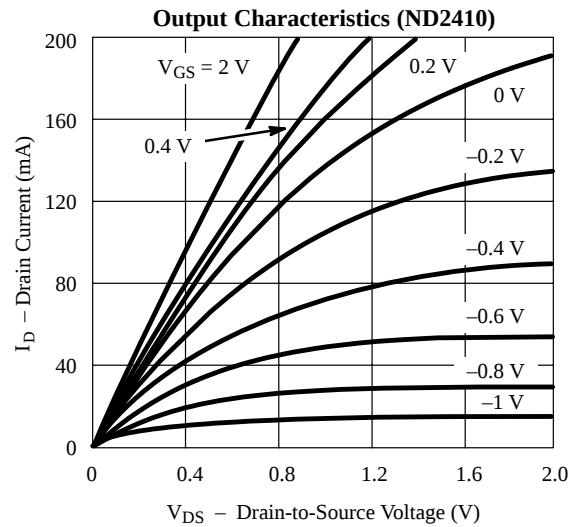
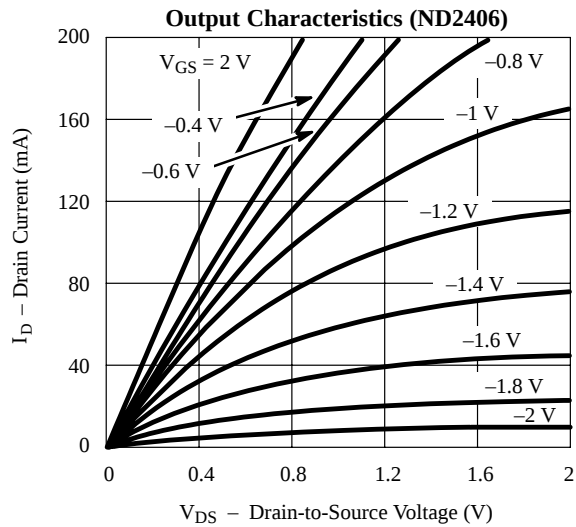
### Notes

- $T_A = 25^\circ\text{C}$  unless otherwise noted.
- For DESIGN AID ONLY, not subject to production testing.
- Pulse test:  $PW \leq 300\text{ }\mu\text{s}$  duty cycle  $\leq 2\%$ .
- Switching time is essentially independent of operating temperature.

VDDV24

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## Typical Characteristics (25°C Unless Otherwise Noted)



# ND2406L/2410L, BSS129

## Typical Characteristics (25°C Unless Otherwise Noted) (Cont'd)

